



MGBR20L30C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

■ DESCRIPTION

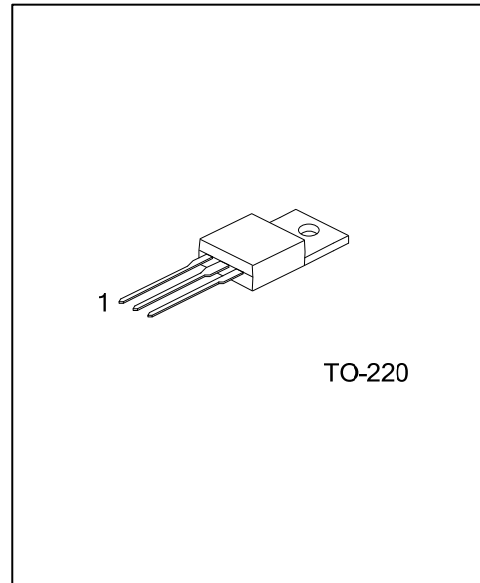
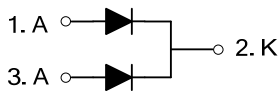
The UTC **MGBR20L30C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

The UTC **MGBR20L30C** suitable for supply applications.

■ FEATURES

- * Low forward voltage drop
- * High switching speed

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
MGBR20L30CL-TA3-T	MGBR20L30CG-TA3-T	TO-220	A	K	A	Tube

Note: Pin Assignment: A: Anode, K: Cathode

<p>MGBR20L30CL-TA3-T</p>	<p>(1) T: Tube</p> <p>(2) TA3: TO-220</p> <p>(3) L: Lead Free, G: Halogen Free</p>
--------------------------	--

■ MARKING INFORMATION

PACKAGE	MARKING
TO-220	

■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _{RM}	30	V
Working Peak Reverse Voltage		V _{RWM}	30	V
Peak Repetitive Reverse Voltage		V _{RRM}	30	V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% Duty Cycle	Per Leg	I _O	10	A
	Total		20	A
Peak Forward Surge Current - 1/2 60hz		I _{FSM}	170	A
Maximum Rate of Voltage Change (at Rated V _R)		dv/dt	10000	V/μS
Operating Junction Temperature		T _J	-65~+150	°C
Storage Junction Temperature		T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ _{JA}	62.5	°C/W
Junction to Case	θ _{JC}	2	°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	30			V
Forward Voltage	V _{FM}	I _F =10A, T _J =25°C			0.55	V
		I _F =10A, T _J =125°C			0.51	V
Reverse Current (Note 1)	I _{RM}	V _R =30V, T _J =25°C			200	μA
		V _R =30V, T _J =125°C			50	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.